

Specifications AHF2803R3S

Absolute Maximum Ratings	
Input Voltage	-0.5Vdc to +50V _{DC}
Soldering temperature	+300°C for 10 seconds
Operating case temperature	-55°C to +125°C
Storage case temperature	-65°C to +135°C

Table I. Electrical Performance Characteristics

Parameter	Cymab al	Conditions -55°C ≤ T _C ≤ +125°C	Group A	Davisa	Limits		Unit
Parameter		$V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ Unless otherwise specified	Subgroups	Device Types	Min	Max	Onit
Output voltage	W	V _{OUT} I _{OUT} = 5% of rated load	01	3.26	3.34		
Output voltage	VOUT	10UT - 5 % of fateu load	2,3	01	3.23	3.36	V
Output current ¹	I _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		3030	mA
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		10	W
Output ripple voltage ²	V _{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p
Line regulation	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 5%, 50% and 100% rated load	1,2,3	01		25	mV
Load regulation	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 5%, 50% and 100% rated load	1,2,3	01		50	mV
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA
·		I _{OUT} = 0, Inhibit (Pin 1) = open				30	
Input ripple current ²	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p
Efficiency	E _{FF}	I _{OUT} = 100% rated load	1	01	70		%
			2,3		68		70
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01	100		ΜΩ
Capacitive load ^{3,4}	C _L	No effect on dc performance, $T_C = +25^{\circ}C$	4	01		500	μF
Power dissipation	P _D	Overload ⁵	1	01		6.0	W
load fault		Short circuit	1,2,3	01		2.0	
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz



Table I. Electrical Performance Characteristics (continued)

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Davameter	0	Conditions -55°C ≤ T _C ≤ +125°C	0	Bassian	Limits		1124
Parameter	Symbol	Symbol $V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ unless otherwise specified $C_{IN} = 0$ Subgroups	Device Types	Min	Max	Unit	
Output response to step transient load	VO _{TLOAD}	50% to/from 100% rated load	4,5,6	01	-300	+300	mVpk
changes ⁶	TOTEOAD	5% to/from 50% rated load	4,5,6		-500	+500	
Recovery time step	TT _{LOAD}	50% to/from 100% rated load	4,5,6			70	μs
transient load changes ^{6.7}		5% to 50% rated load	4,5,6	01		1200	μs
		50% to 5% rated load	4,5,6			8.0	ms
Output response to transient step line changes	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 8}	4,5,6	01		500	mVpk
Recovery time transient step line changes	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 7, 8}	4,5,6	01		800	μs
Turn on overshoot	VTonos	I _{OUT} = 5 and 100% rated load	4,5,6	01		600	mVpk
Turn on delay	Ton _D	I _{OUT} = 5 and 100% rated load ⁹	4,5,6	01		20	ms
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		20	ms
Weight						38	g

Notes to Table I:

- 1. Parameter guaranteed by line and load regulation tests.
- 2. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 3. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- 4. Parameter shall be tested as part of design characterization and after design or process changes. Thereafter, parameters shall be guaranteed to the limits specified in Table I.
- 5. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 6. Load step transition time between 2 and 10 microseconds.
- Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load.
- 8. Input step transition time between 2 and 10 microseconds.
- 9. Turn-on delay time measurement is for either a step application of power at the input or the removal of ground signal from the Inhibit Pin (Pin 1) while power is applied to the input is unlimited.



Specifications AHF2805S

Absolute Maximum Ratings					
Input Voltage	-0.5Vdc to +50V _{DC}				
Soldering temperature	+300°C for 10 seconds				
Operating case temperature	-55°C to +125°C				
Storage case temperature	-65°C to +135°C				

Table II. Electrical Performance Characteristics

Parameter	Complete of	Conditions -55°C ≤ T _C ≤ +125°C	Group A Subgroups	Davisa	Lir	nits	11:4
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ Unless otherwise specified		Device Types	Min	Max	Unit
Output voltage	V _{OUT}	I _{OUT} = 0	1	01	4.95	5.05	
Output Voltage	V OUT	1001 = 0	2,3	01	4.90	5.10	V
Output current ¹	I _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		2400	mA
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W
Output ripple voltage ²	V _{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p
Line regulation	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		25	mV
Load regulation	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		50	mV
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA
·		I _{OUT} = 0, Inhibit (Pin 1) = open				30	
Input ripple current ²	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p
Efficiency	E _{FF}	I _{OUT} = 100% rated load	1	01	76		%
			2,3		74		70
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01	100		ΜΩ
Capacitive load ^{3,4}	C _L	No effect on dc performance, T _C = +25°C	4	01		500	μF
Power dissipation	P _D	Overload ⁵	1	01		6.0	W
load fault		Short circuit	1,2,3	01		2.0	
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz



Table II. Electrical Performance Characteristics (continued)

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Barrantan	0	Conditions -55°C ≤ T _C ≤ +125°C	Group A	Croup A	Crown A	Bassian	Limits		1124
Parameter	Symbol		Device Types	Min	Max	Unit			
Output response to step transient load	VO_{TLOAD}	50% to/from 100% rated load	4,5,6	01	-300	+300	mVpk		
changes ⁶	- TEOAD	0% to/from 50% rated load	4,5,6		-500	+500			
Recovery time step	TT _{LOAD}	50% to/from 100% rated load	4,5,6			70	μs		
transient load changes ^{6.7}		0% to 50% rated load	4,5,6	01		1200	μs		
		50% to 0% rated load	4,5,6			8.0	ms		
Output response to transient step line changes	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 8}	4,5,6	01		500	mVpk		
Recovery time transient step line changes	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 7, 8}	4,5,6	01		800	μs		
Turn on overshoot	VTon _{os}	I _{OUT} = 0 and 100% rated load	4,5,6	01		600	mVpk		
Turn on delay	Ton _D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		20	ms		
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		20	ms		
Weight						38	g		

Notes to Table II:

- 1. Parameter guaranteed by line and load regulation tests.
- 2. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 3. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- Parameter shall be tested as part of design characterization and after design or process changes.
 Thereafter, parameters shall be guaranteed to the limits specified in Table II.
- 5. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 6. Load step transition time between 2 and 10 microseconds.
- Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load.
- 8. Input step transition time between 2 and 10 microseconds.
- 9. Turn-on delay time measurement is for either a step application of power at the input or the removal of ground signal from the Inhibit Pin (Pin 1) while power is applied to the input is unlimited.



Specifications AHF2812S

Absolute Maximum Ratings					
Input Voltage	-0.5Vdc to +50V _{DC}				
Soldering temperature	+300°C for 10 seconds				
Operating case temperature	-55°C to +125°C				
Storage case temperature	-65°C to +135°C				

Table III. Electrical Performance Characteristics

Dava-matar.	0	Conditions $-55^{\circ}C \le T_{c} \le +125^{\circ}C$	0	D	Lir	nits	1114	
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%, C_L = 0$ Unless otherwise specified	Group A Subgroups	Device Types	Min	Max	Unit	
Output voltage	V_{OUT}	I _{OUT} = 0	1	01	11.88	12.12		
Output voltage	V OUT	IOUT - U	2,3	01	11.76	12.24	V	
Output current ¹	I _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		1000	mA	
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W	
Output ripple voltage ²	V_{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p	
Line regulation	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		50	mV	
Load regulation	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		50	mV	
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA	
,		I _{OUT} = 0, Inhibit (Pin 1) = open				50		
Input ripple current ²	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p	
Efficiency	E _{FF}	I _{OUT} = 100% rated load	1	01	78		%	
			2,3		75		70	
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01	100		МΩ	
Capacitive load ^{3,4}	C _L	No effect on dc performance, $T_C = +25^{\circ}C$	4	01		200	μF	
Power dissipation	P _D	Overload ⁵	1	01		6.0	W	
load fault		Short circuit	1,2,3	01		2.0		
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz	

For Notes to Electrical Performance Characteristics, refer to page 7

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Table III. Electrical Performance Characteristics (continued)

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Borometer	0		0	D	Lir	nits	1124
Parameter	Symbol		Subgroups	Device Types	Min	Max	Unit
		50% to/from 100% rated load	4		-300	+300	
Output response to	VO	50% to/ffofff 100% rated load —	5,6	01	-450	+450	m)/nk
step transient load changes ⁶	VO _{TLOAD}	0% to/from 50% rated load	4	01	-500	+500	mVpk
		0% to/from 50% rated load	5,6		-750	+750	
Recovery time step	TT _{LOAD}	50% to/from 100% rated load	4,5,6			100	μs
transient load changes ^{6.7}	IILOAD	0% to 50% rated load	4,5,6	01		1500	μs
onunges		50% to 0% rated load	4,5,6			10	ms
Output response to transient step line changes	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 8}	4,5,6	01		1500	mVpk
Recovery time transient step line changes	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 7, 8}	4,5,6	01		800	μs
Turn on overshoot	VTon _{OS}	I _{OUT} = 0 and 100% rated load	4,5,6	01		600	mVpk
Turn on delay	Ton _D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		20	ms
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		20	ms
Weight						38	g

Notes to Table III:

- 1. Parameter guaranteed by line and load regulation tests.
- 2. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 3. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- 4. Parameter shall be tested as part of design characterization and after design or process changes. Thereafter, parameters shall be guaranteed to the limits specified in Table III.
- 5. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 6. Load step transition time between 2 and 10 microseconds.
- 7. Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load.
- 8. Input step transition time between 2 and 10 microseconds.
- 9. Turn-on delay time measurement is for either a step application of power at the input or the removal of ground signal from the Inhibit Pin (Pin 1) while power is applied to the input is unlimited.



Specifications AHF2815S

Absolute Maximum Ratings					
Input Voltage	-0.5Vdc to +50V _{DC}				
Soldering temperature	+300°C for 10 seconds				
Operating case temperature	-55°C to +125°C				
Storage case temperature	-65°C to +135°C				

Table IV. Electrical Performance Characteristics

Parameter		O1101111 A	Davis	Limits		11-4		
		$V_{IN} = 28 V_{DC} \pm 5\%, C_{L} = 0$	Group A Subgroups	Device Types	Min	Max	Unit	
Output voltage	V _{OUT}	I _{OUT} = 0	1	01	14.85	15.15		
Output voltage	VOUT	IOUT - U	2,3	01	14.70	15.30	V	
Output current ¹	I _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		800	mA	
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W	
Output ripple voltage ²	V _{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p	
Line regulation	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		50	mV	
Load regulation	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		50	mV	
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA	
·		I _{OUT} = 0, Inhibit (Pin 1) = open	, ,				40	
Input ripple current ²	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p	
Efficiency	E _{FF}	I _{OUT} = 100% rated load	1	01	78		%	
·			2,3		75		70	
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01	100		ΜΩ	
Capacitive load ^{3,4}	C _L	No effect on dc performance, T _C = +25°C	4	01		200	μF	
Power dissipation	P _D	Overload ⁵	1	01		6.0	W	
load fault		Short circuit	1,2,3	01		2.0		
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz	



Table IV. Electrical Performance Characteristics (continued)

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Parameter		Conditions -55°C ≤ T _C ≤ +125°C			Limits		Unit
	Symbol		Device Types	Min	Max	Unit	
Output response to step transient load	VO_{TLOAD}	50% to/from 100% rated load	4,5,6	01	-300	+300	mVpk
changes ⁶	- TEOAD	0% to/from 50% rated load	4,5,6		-750	+750	
Recovery time step	TT _{LOAD}	50% to/from 100% rated load	4,5,6			100	μs
transient load changes ^{6.7}		0% to 50% rated load	4,5,6	01		1500	μs
		50% to 0% rated load	4,5,6			10	ms
Output response to transient step line changes	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 8}	4,5,6	01	-1500	+1500	mVpk
Recovery time transient step line changes	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load ^{4, 7, 8}	4,5,6	01		800	μs
Turn on overshoot	VTonos	I _{OUT} = 0 and 100% rated load	4,5,6	01		750	mVpk
Turn on delay	Ton _D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		20	ms
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		20	ms
Weight						38	g

Notes to Table IV:

- 1. Parameter guaranteed by line and load regulation tests.
- 2. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 3. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- 4. Parameter shall be tested as part of design characterization and after design or process changes. Thereafter, parameters shall be guaranteed to the limits specified in Table IV.
- 5. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 6. Load step transition time between 2 and 10 microseconds.
- Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load.
- 8. Input step transition time between 2 and 10 microseconds.
- 9. Turn-on delay time measurement is for either a step application of power at the input or the removal of ground signal from the Inhibit Pin (Pin 1) while power is applied to the input is unlimited.



Specifications AHF2805D

Absolute Maximum Ratings				
Input Voltage	-0.5Vdc to +50V _{DC}			
Soldering temperature	+300°C for 10 seconds			
Operating case temperature	-55°C to +125°C			
Storage case temperature	-65°C to +135°C			

Table V. Electrical Performance Characteristics

Daramatar	Symbol	Conditions $-55^{\circ}C \le T_{C} \le +125^{\circ}C$ Symbol		Device	Limits		Unit	
Parameter	Symbol	V_{IN} = 28 V_{DC} ± 5%, C_L = 0 Unless otherwise specified	Group A Subgroups	Types	Min	Max	Onit	
Outrot valle as	.,,		1	04	±4.95	±5.05		
Output voltage	V _{OUT}	I _{OUT} = 0	2,3	01	±4.90	±5.10	V	
Output current ^{1,2}	I _{OUT}	V _{IN} = 16, 28, and 40Vdc, each output	1,2,3	01	120	1080	mA	
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W	
Output ripple voltage ³	V_{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p	
Line regulation ⁴	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		30	mV	
Load regulation ⁴	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		30	mV	
Cross regulation ⁵	VR _{CROSS}	10% to 90% load changes	1,2,3	01		±10	%	
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA	
mpat ourient	IIIV	I _{OUT} = 0, Inhibit (Pin 1) = open	1,2,0	01		60		
Input ripple current ^{3,4}	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p	
Efficiency ⁴	E _{FF}	E _{FF} I _{OUT} = 100% rated load	1,3	01	75		%	
,		1001	2		72		70	
Isolation	ISO	Input to output or any pin to case (except Pin 6) at $500Vdc T_C = +25^{\circ}C$	1	01	100		ΜΩ	
Capacitive load ^{6,7}	C _L	No effect on dc performance, $T_C = +25^{\circ}C$	4	01		200	μF	
Power dissipation	P _D Ov	Overload	400	01		6.0	W	
load fault	. 0	Short circuit	1,2,3	01		2.0		
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz	

For Notes to Electrical Performance Characteristics, refer to page 11

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Table V. Electrical Performance Characteristics (continued)

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Downwater	Sumah al	Symbol Conditions $-55^{\circ}C \le T_{C} \le +125^{\circ}C$		Davisa	Limits		l lni4
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%, C_L = 0$ unless otherwise specified	Group A Subgroups	Device Types	Min	Max	Unit
Output response to step transient load	VO_{TLOAD}	50% to/from 100% rated load	4,5,6	01	-400	+400	mVpk
changes ^{4, 9}	TLOAD	0% to/from 50% rated load	4,5,6		-800	+800	vp.x
Recovery time step	TT_LOAD	50% to/from 100% rated load	4,5,6	0.4		100	μs
transient load changes 4, 9, 10		0% to 50% rated load	4,5,6	01		5000	μs
Output response to transient step line changes ^{4, 7, 11}	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01	-400	+400	mVpk
Recovery time transient step line changes ^{4, 7, 10, 11}	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01		1200	μs
Turn on overshoot ⁴	VTon _{OS}	I _{OUT} = 0 and 100% rated load	4,5,6	01		600	mVpk
Turn on delay	Ton_D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		25	ms
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		25	ms
Weight						38	g

Notes to Table V:

- 1. Parameter guaranteed by line load and cross regulation tests.
- 2. Up to 90 percent of full power is available from either output provided the total output does not exceed 12W.
- 3. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- Load current split equally between +V_{OUT} and -V_{OUT}.
- 5. 1.2 watt load on output under test, 1.2 watt to 10.8 watt load change on other output.
- 6. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance.
 - A capacitive load in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- Parameter shall be tested as part of design characterization and after design or process changes.
 Thereafter, parameters shall be guaranteed to the limits specified in Table V.
- 8. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 9. Load step transition time between 2 and 10 microseconds.
- 10. Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load
- 11. Input step transition time between 2 and 10 microseconds.
- 12. Turn-on delay time measurement is for either a step application of power at the input or the removal of a ground signal from the Inhibit Pin (Pin 1) while power is applied to the input.



Specifications AHF2812D

Absolute Maximum Ratings					
Input Voltage	-0.5Vdc to +50V _{DC}				
Soldering temperature	+300°C for 10 seconds				
Operating case temperature	-55°C to +125°C				
Storage case temperature	-65°C to +135°C				

Table VI. Electrical Performance Characteristics

Davamatav	Symbol	Conditions -55°C ≤ T _C ≤ +125°C	Croup A	Group A Device		Limits	
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ Unless otherwise specified	Subgroups	Types	Min	Max	Unit
Output valtage		1 -0	1	0.1	±11.88	±12.12	
Output voltage	V _{OUT}	I _{OUT} = 0	2,3		±11.76	±12.24	V
Output current ^{1,2}	I _{OUT}	V _{IN} = 16, 28, and 40Vdc, each output	1,2,3	01	100	900	mA
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W
Output ripple voltage ³	V_{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p
Line regulation ⁴	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		30	mV
Load regulation ⁴	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		30	mV
Cross regulation ⁵	VR _{CROSS}	10% to 90% load changes	1,2,3	01		3.0	%
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA
mpat darront	IIN	I _{OUT} = 0, Inhibit (Pin 1) = open	1,2,0	01		60	
Input ripple current ^{3,4}	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p
Efficiency ⁴	E _{FF}	I _{OUT} = 100% rated load	1,3	01	77	%	
,		001	2		74		70
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01	100		ΜΩ
Capacitive load ^{6,7}	C _L	No effect on dc perfor- mance, T _C = +25°C	4	01		200	μF
Power dissipation	P_{D}	Overload	122	01		6.0	W
load fault	۵ -	Short circuit	1,2,3	UI		3.0	.,
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz



Table VI. Electrical Performance Characteristics (continued)

AHF2812D

		Conditions -55°C ≤ T _C ≤ +125°C			Limits		1124
Parameter	Neter Symbol $V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ unless otherwise specified Subgroups		Group A Subgroups	Device Types	Min	Max	Unit
Output response to step transient load	VO_{TLOAD}	50% to/from 100% rated load	4,5,6	01	-200	+200	mVpk
changes ^{4, 9}	• • TEOAD	0% to/from 50% rated load	4,5,6		-800	+800	vp.x
Recovery time step	TT_LOAD	50% to/from 100% rated load	4,5,6	0.4		70	μs
transient load changes 4, 9, 10		0% to 50% rated load	4,5,6	01		2000	μs
Output response to transient step line changes ^{4, 7, 11}	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01	-750	+750	mVpk
Recovery time transient step line changes ^{4, 7, 10, 11}	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01		1200	μѕ
Turn on overshoot ⁴	VTon _{OS}	I _{OUT} = 0 and 100% rated load	4,5,6	01		600	mVpk
Turn on delay	Ton_D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		25	ms
Load fault recovery ^{4,9}	Tr_{LF}		4,5,6	01		25	ms
Weight						38	g

Notes to Table VI:

- 1. Parameter guaranteed by line load and cross regulation tests.
- 2. Up to 90 percent of full power is available from either output provided the total output does not exceed 12W.
- 3. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 4. Load current split equally between $+V_{OUT}$ and $-V_{OUT}$.
- 5. 1.2 watt load on output under test, 1.2 watt to 10.8 watt load change on other output.
- 6. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance.
 - A capacitive load in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- 7. Parameter shall be tested as part of design characterization and after design or process changes. Thereafter, parameters shall be guaranteed to the limits specified in Table VI.
- 8. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 9. Load step transition time between 2 and 10 microseconds.
- 10. Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ± 1 percent of V_{OUT} at 50 percent
- 11. Input step transition time between 2 and 10 microseconds.
- 12. Turn-on delay time measurement is for either a step application of power at the input or the removal of a ground signal from the Inhibit Pin (Pin 1) while power is applied to the input.



Specifications AHF2815D

Absolute Maximum Ratings				
Input Voltage	-0.5Vdc to +50V _{DC}			
Soldering temperature	+300°C for 10 seconds			
Operating case temperature	-55°C to +125°C			
Storage case temperature	-65°C to +135°C			

Table VII. Electrical Performance Characteristics

Davamatav	Symbol	Conditions -55°C ≤ T _C ≤ +125°C	Crown A	Davisa	Limits		11:4
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%$, $C_L = 0$ Unless otherwise specified	Group A Subgroups	Device Types	Min	Max	Unit
Output voltage		1 -0	1	01	±14.85	±15.15	
Output voltage	V _{OUT}	I _{OUT} = 0	2,3	01	±14.70	±15.30	V
Output current ^{1,2}	I _{OUT}	V _{IN} = 16, 28, and 40Vdc, each output	1,2,3	01	80	720	mA
Output power	P _{OUT}	V _{IN} = 16, 28, and 40Vdc	1,2,3	01		12	W
Output ripple voltage ³	V_{RIP}	V _{IN} = 16, 28, and 40Vdc, B.W. = 20 Hz to 2MHz	1,2,3	01		60	mVp-p
Line regulation ⁴	VR _{LINE}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		35	mV
Load regulation ⁴	VR _{LOAD}	V _{IN} = 16, 28, and 40Vdc, I _{OUT} = 0, 50% and 100% rated load	1,2,3	01		35	mV
Cross regulation ⁵	VR _{CROSS}	10% to 90% load changes	1,2,3	01		3.0	%
Input current	I _{IN}	I _{OUT} = 0, Inhibit (Pin 1) tied to Input Return (Pin 7)	1,2,3	01		12	mA
input ouriont	IIN	I _{OUT} = 0, Inhibit (Pin 1) = open	1,2,0			60	
Input ripple current ^{3,4}	I _{RIP}	I _{OUT} = 100% rated load B.W. = 20 Hz to 2 MHz	1,2,3	01		50	mAp-p
Efficiency ⁴	E _{FF}	I _{OUT} = 100% rated load	1,3	01	78		%
,			2		74		70
Isolation	ISO	Input to output or any pin to case (except Pin 6) at 500Vdc T _C = +25°C	1	01 100			MΩ
Capacitive load ^{6,7}	C _L	No effect on dc perfor- mance, T _C = +25°C	4	01		200	μF
Power dissipation	P _D	Overload	123	01		6.0	W
load fault	5	Short circuit	1,2,3 01			2.5	-
Switching frequency	Fs	I _{OUT} = 100% rated load	4,5,6	01	500	600	kHz



Table VII. Electrical Performance Characteristics (continued)

AHF2815D

D	Symbol Conditions $-55^{\circ}C \le T_{C} \le +125^{\circ}C$		0	Davida	Limits		Unit	
Parameter	Symbol	$V_{IN} = 28 V_{DC} \pm 5\%, C_L = 0$ unless otherwise specified	Group A Subgroups	Device Types	Min	Max	Unit	
Output response to step transient load	VO _{TLOAD}	50% to/from 100% rated load	4,5,6	01	-200	+200	mVpk	
changes ^{4, 9}	T O TEOAD	0% to/from 50% rated load	4,5,6		-800	+800		
Recovery time step	TT _{LOAD}	50% to/from 100% rated load	4,5,6	04		70	μs	
transient load changes 4, 9, 10		0% to 50% rated load	4,5,6	01		2000	рs	
Output response to transient step line changes ^{4, 7, 11}	VO _{TLINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01	-750	+750	mVpk	
Recovery time transient step line changes ^{4, 7, 10, 11}	TT _{LINE}	Input step 16V to/from 40Vdc, I _{OUT} = 100% rated load	4,5,6	01		1200	μs	
Turn on overshoot ⁴	VTon _{OS}	I _{OUT} = 0 and 100% rated load	4,5,6	01		750	mVpk	
Turn on delay	Ton _D	I _{OUT} = 0 and 100% rated load ⁹	4,5,6	01		25	ms	
Load fault recovery ^{4,9}	Tr _{LF}		4,5,6	01		25	ms	
Weight						38	g	

Notes to Table VII:

- 1. Parameter guaranteed by line load and cross regulation tests.
- 2. Up to 90 percent of full power is available from either output provided the total output does not exceed 12W.
- 3. Bandwidth guaranteed by design. Tested for 20kHz to 2MHz.
- 4. Load current split equally between +V_{OUT} and -V_{OUT}.
- 5. 1.2 watt load on output under test, 1.2 watt to 10.8 watt load change on other output.
- 6. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance.
 - A capacitive load in excess of the maximum limit will not disturb loop stability but may interfere with the operation of the load fault detection circuitry, appearing as a short circuit during turn-on.
- 7. Parameter shall be tested as part of design characterization and after design or process changes.
 - Thereafter, parameters shall be guaranteed to the limits specified in Table VII.
- 8. An overload is that condition with a load in excess of the rated load but less than that necessary to trigger the short circuit protection and is the condition of maximum power dissipation.
- 9. Load step transition time between 2 and 10 microseconds.
- 10. Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1 percent of V_{OUT} at 50 percent load.
- 11. Input step transition time between 2 and 10 microseconds.
- 12. Turn-on delay time measurement is for either a step application of power at the input or the removal of a ground signal from the Inhibit Pin (Pin 1) while power is applied to the input.



Application Information

Inhibit Function (Enable)

Connecting the Enable Input (Pin 1) to Input Common (Pin 7) will cause the converter to shut down. It is recommended that the Enable Pin be driven by an open collector device capable of sinking at least $400\mu A$ of current. The open circuit voltage of the Enable Input is $15\pm1.0V_{DC}$. If the Inhibit function is not used, this Input can be left unconnected because it is internally pulled-up.

Thermal Management

Assuming that there is no forced air flow, the package temperature rise above ambient (ΔT) may be calculated using the following expression:

$$\Delta T \approx 80 \text{ A}^{-0.7} \text{p}^{0.85} \text{ (°C)}$$

where A = Effective surface area in square inches (including heat sink if used), P = Power dissipation in watts.

The total surface area of the AHF package is 4.9 square inches. If a worst case full load efficiency of 78% is assumed, then the case temperature rise can be calculated as follows:

$$P = P_{OUT} \left[\frac{1}{Eff} - 1 \right] = 12 \left[\frac{1}{0.78} - 1 \right] = 3.4W$$

$$\Delta T = 80 (4.9)^{-0.7} (3.4)^{0.85} = 74^{\circ}C$$

Hence if T_{AMBIENT} = +25°C, the DC-DC converter case temperature will be approximately 100°C if no heat sink or air flow is provided.

To calculate the heat sink area required to maintain a specific case temperature rise, the above equation may be manipulated as follows:

$$\mathsf{A}_{\mathsf{HEAT\,SINK}} = \left[\frac{\Delta T}{80P^{0.85}}\right]^{-1.43} - \mathsf{A}_{\mathit{PKG}}$$

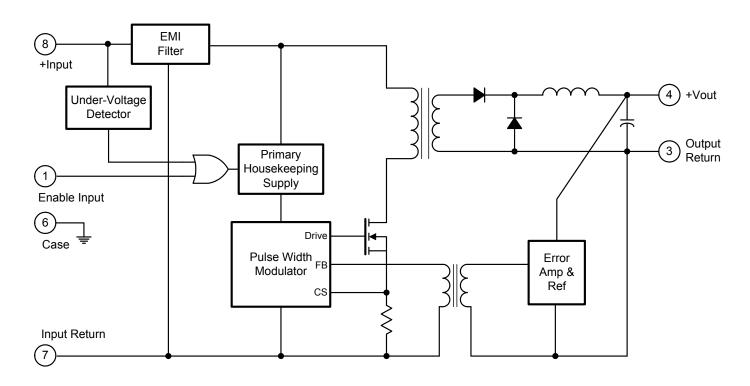
As an example, if a maximum case temperature rise of 50°C above ambient is desired, then the required effective heat sink area is:

$$A_{HEATSINK} = \left[\frac{50}{80(3.4)^{0.85}} \right]^{-1.43} - 4.9 = 3.75 in.^{2}$$

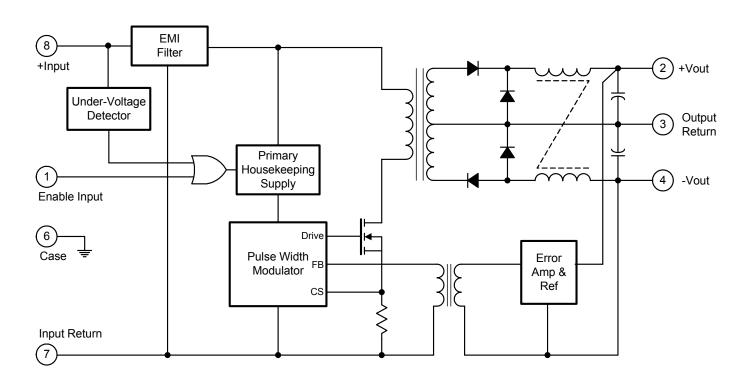


Block Diagrams

Single Output

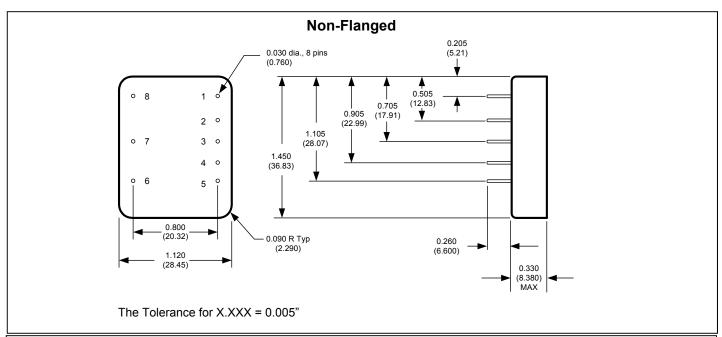


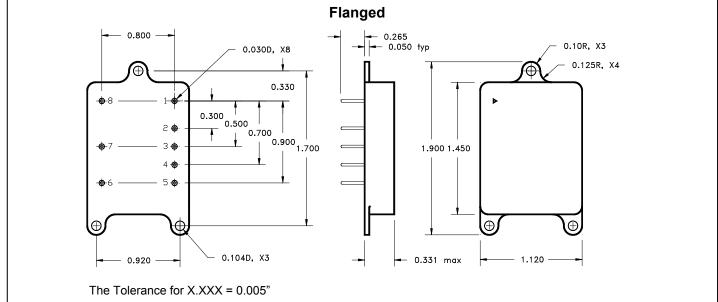
Dual Output





Mechanical Outlines





Pin Designation Tables

Standard Microcircuit Drawing Equivalence Table

Single Output

3					
Pin #	Designation				
1	Enable Input				
2	NC				
3	Output Return				
4	+Output				
5	NC				
6	Case Ground				
7	Input Return				
8	+Input				

Pin#	Designation			
1	Enable Input			
2	+Output			
3	Output Return			
4	-Output			
5	NC			
6	Case Ground			
7	Input Return			
8	+Input			

Dual Output

Standard Microcircuit	Vendor Cage	IR Hirel Standard
Drawing Number	Code	Part Number
5962-91600	52467	AHF2805S
5962-94568	52467	AHF2812S
5962-94563	52467	AHF2815S
5962-05205	52467	AHF2805D
5962-92111	52467	AHF2812D
5962-92351	52467	AHF2815D



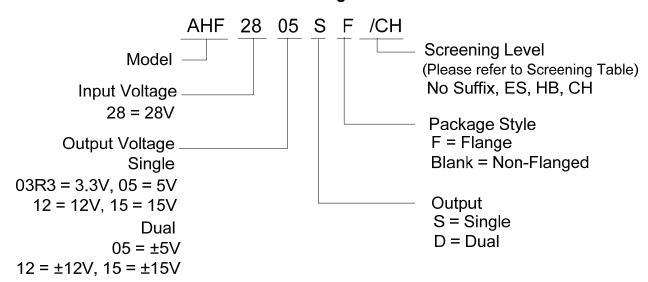
Device Screening

Requirement	MIL-STD-883 Method	No Suffix	ES ②	НВ	СН
Temperature Range	_	-20°C to +85°C	-55°C to +125°C3	-55°C to +125°C	-55°C to +125°C
Element Evaluation	MIL-PRF-38534	N/A	N/A	N/A	Class H
Non-Destructive Bond Pull	2023	N/A	N/A	N/A	N/A
Internal Visual	2017	①	Yes	Yes	Yes
Temperature Cycle	1010	N/A	Cond B	Cond C	Cond C
Constant Acceleration	2001, Y1 Axis	N/A	500 Gs	3000 Gs	3000 Gs
PIND	2020	N/A	N/A	N/A	N/A
Burn-In	1015	N/A	48 hrs @ hi temp	160hrs @ 125°C	160 hrs @ 125°C
Final Electrical (Group A)	MIL-PRF-38534 & Specification	25°C	25°C	-55°C, +25°C, +125°C	-55°C, +25°C, +125°C
PDA	MIL-PRF-38534	N/A	N/A	N/A	10%
Seal, Fine and Gross	1014	Cond A	Cond A, C	Cond A, C	Cond A, C
Radiographic	2012	N/A	N/A	N/A	N/A
External Visual	2009	①	Yes	Yes	Yes

Notes:

- ① Best commercial practice.
- ② Sample tests at low and high temperatures.
- 3 -55°C to +105°C for AHE, ATO, ATW.

Part Numbering





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